NSN 5961-01-018-7009

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-018-7009 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1500.0 breakdown voltage, collector-to-base, emitter open and 750.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 100.00 milliamperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 12.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: